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# DATA SHEET

For a complete data sheet, please also download:

- The IC04 LOCMOS HE4000B Logic Family Specifications HEF, HEC
- The IC04 LOCMOS HE4000B Logic Package Outlines/Information HEF, HEC

## **HEF4066B** **gates** Quadruple bilateral switches

Product specification  
File under Integrated Circuits, IC04

January 1995

Quadruple bilateral switches

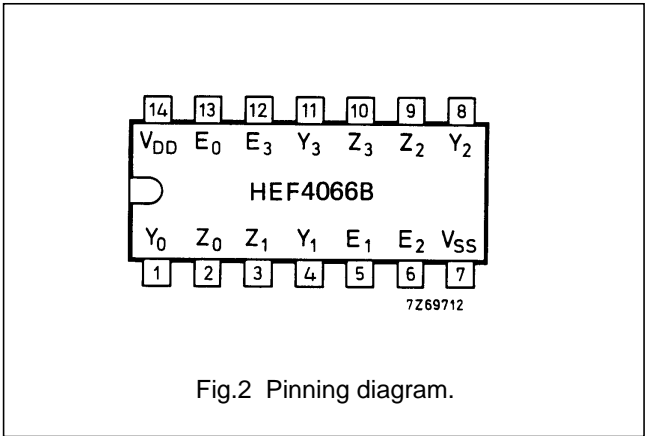
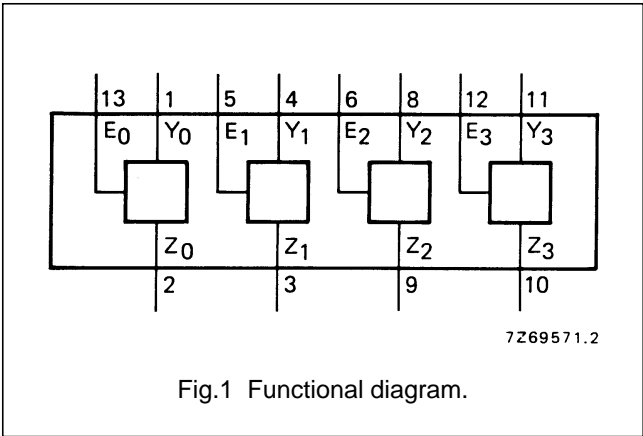
HEF4066B  
gates

DESCRIPTION

The HEF4066B has four independent bilateral analogue switches (transmission gates). Each switch has two input/output terminals (Y/Z) and an active HIGH enable input (E). When E is connected to  $V_{DD}$  a low impedance bidirectional path between Y and Z is established (ON condition). When E is connected to  $V_{SS}$  the switch is

disabled and a high impedance between Y and Z is established (OFF condition).

The HEF4066B is pin compatible with the HEF4016B but exhibits a much lower ON resistance. In addition the ON resistance is relatively constant over the full input signal range.



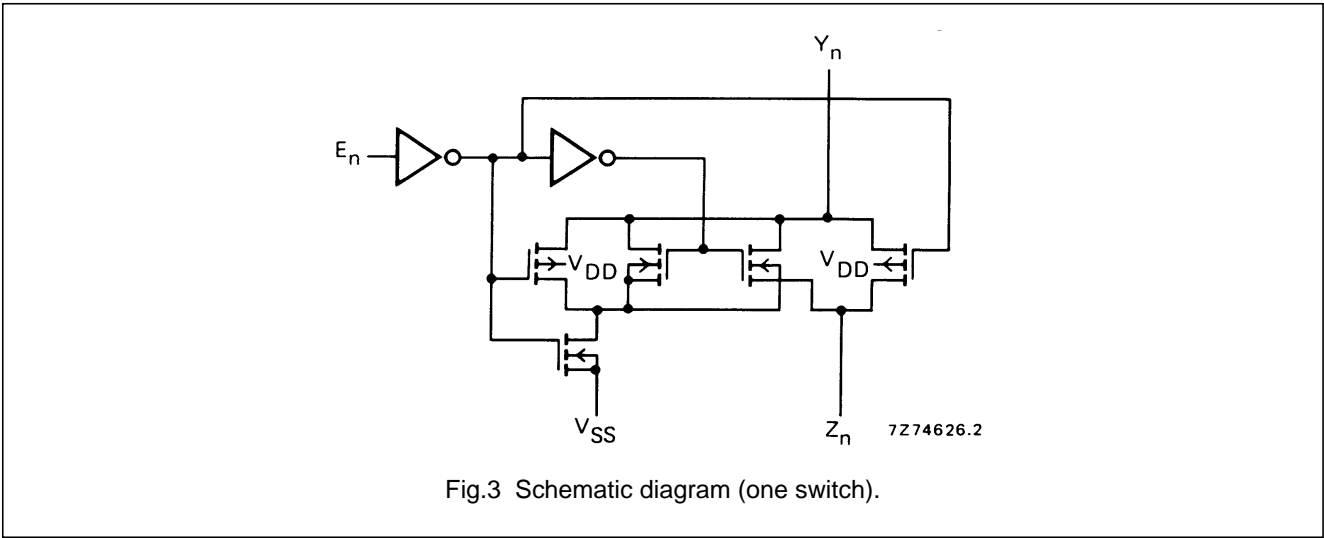
- HEF4066BP(N): 14-lead DIL; plastic (SOT27-1)
- HEF4066BD(F): 14-lead DIL; ceramic (cerdip) (SOT73))
- HEF4066BT(D): 14-lead SO; plastic (SOT108-1)
- ( ): Package Designator North America

PINNING

- $E_0$  to  $E_3$  enable inputs
- $Y_0$  to  $Y_3$  input/output terminals
- $Z_0$  to  $Z_3$  input/output terminals

APPLICATION INFORMATION

- An example of application for the HEF4066B is:
- Analogue and digital switching



# Quadruple bilateral switches

## HEF4066B gates

### RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Power dissipation per switch

P max. 100 mW

For other RATINGS see Family Specifications

### DC CHARACTERISTICS

T<sub>amb</sub> = 25 °C

	V <sub>DD</sub> V	SYMBOL	MIN.	TYP.	MAX.	CONDITIONS
ON resistance	5	R <sub>ON</sub>	–	350	2500 Ω	E <sub>n</sub> at V <sub>DD</sub> V <sub>is</sub> = V <sub>SS</sub> to V <sub>DD</sub> see Fig.4
	10		–	80	245 Ω	
	15		–	60	175 Ω	
ON resistance	5	R <sub>ON</sub>	–	115	340 Ω	E <sub>n</sub> at V <sub>DD</sub> V <sub>is</sub> = V <sub>SS</sub> see Fig.4
	10		–	50	160 Ω	
	15		–	40	115 Ω	
ON resistance	5	R <sub>ON</sub>	–	120	365 Ω	E <sub>n</sub> at V <sub>DD</sub> V <sub>is</sub> = V <sub>DD</sub> see Fig.4
	10		–	65	200 Ω	
	15		–	50	155 Ω	
'Δ' ON resistance between any two channels	5	ΔR <sub>ON</sub>	–	25	– Ω	E <sub>n</sub> at V <sub>DD</sub> V <sub>is</sub> = V <sub>SS</sub> to V <sub>DD</sub> see Fig.4
	10		–	10	– Ω	
	15		–	5	– Ω	
OFF state leakage current, any channel OFF	5	I <sub>OZ</sub>	–	–	– nA	E <sub>n</sub> at V <sub>SS</sub>
	10		–	–	– nA	
	15		–	–	200 nA	
E <sub>n</sub> input voltage LOW	5	V <sub>IL</sub>	–	2,25	1 V	I <sub>is</sub> = 10 μA see Fig.9
	10		–	4,50	2 V	
	15		–	6,75	2 V	

	V <sub>DD</sub> V	SYMBOL	T <sub>amb</sub> (°C)			CONDITIONS
			–40	+25	+85	
			MAX.	MAX.	MAX.	
Quiescent device current	5	I <sub>DD</sub>	1,0	1,0	7,5 μA	V <sub>SS</sub> = 0; all valid input combinations; V <sub>I</sub> = V <sub>SS</sub> or V <sub>DD</sub>
	10		2,0	2,0	15,0 μA	
	15		4,0	4,0	30,0 μA	
Input leakage current at E <sub>n</sub>	15	± I <sub>IN</sub>	–	300	1000 nA	E <sub>n</sub> at V <sub>SS</sub> or V <sub>DD</sub>

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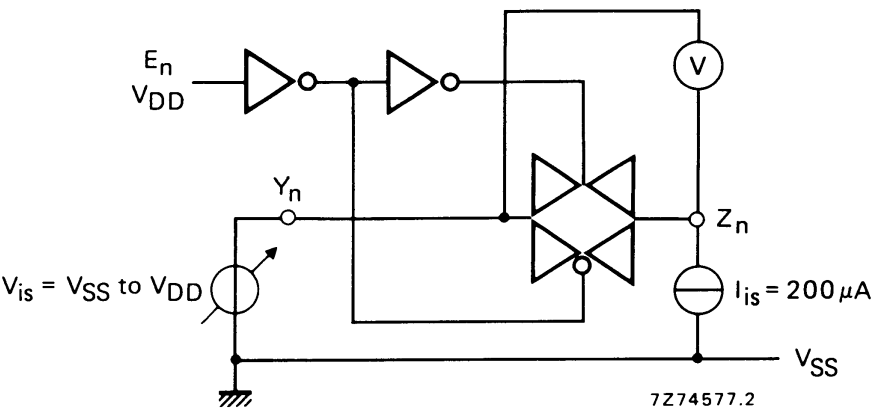


Fig.4 Test set-up for measuring  $R_{ON}$ .

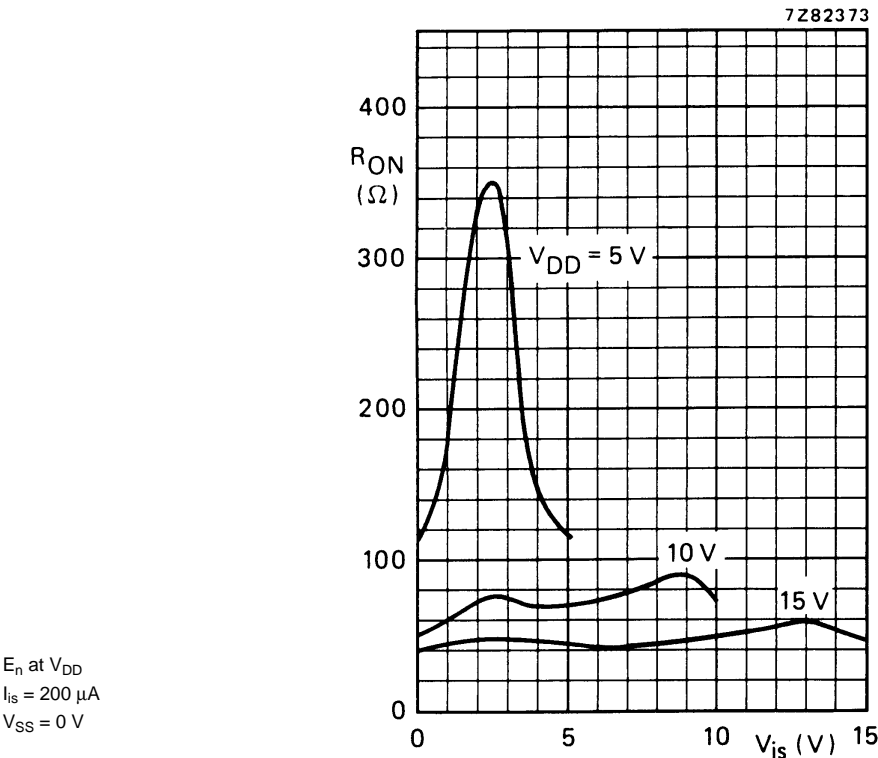


Fig.5 Typical  $R_{ON}$  as a function of input voltage.

NOTE

To avoid drawing  $V_{DD}$  current out of terminal Z, when switch current flows into terminals Y, the voltage drop across the bidirectional switch must not exceed 0,4 V. If the switch current flows into terminal Z, no  $V_{DD}$  current will flow out of terminals Y, in this case there is no limit for the voltage drop across the switch, but the voltages at Y and Z may not exceed  $V_{DD}$  or  $V_{SS}$ .

# Quadruple bilateral switches

## HEF4066B gates

### AC CHARACTERISTICS <sup>(1), (2)</sup>

$V_{SS} = 0\text{ V}$ ;  $T_{amb} = 25\text{ }^{\circ}\text{C}$ ; input transition times  $\leq 20\text{ ns}$

	$V_{DD}$ V	SYMBOL	TYP.	MAX.	
Propagation delays $V_{is} \rightarrow V_{os}$ HIGH to LOW	5	$t_{PHL}$	10	20	ns
	10		5	10	ns
	15		5	10	ns
	5	$t_{PLH}$	10	20	ns
	10		5	10	ns
	15		5	10	ns
Output disable times $E_n \rightarrow V_{os}$ HIGH	5	$t_{PHZ}$	80	160	ns
	10		65	130	ns
	15		60	120	ns
	5	$t_{PLZ}$	80	160	ns
	10		70	140	ns
	15		70	140	ns
Output enable times $E_n \rightarrow V_{os}$ HIGH	5	$t_{PZH}$	40	80	ns
	10		20	40	ns
	15		15	30	ns
	5	$t_{PZL}$	45	90	ns
	10		20	40	ns
	15		15	30	ns
Distortion, sine-wave response	5		0,25		%
	10		0,04		%
	15		0,04		%
Crosstalk between any two channels	5		–		MHz
	10		1		MHz
	15		–		MHz
Crosstalk; enable input to output	5		–		mV
	10		50		mV
	15		–		mV
OFF-state feed-through	5		–		MHz
	10		1		MHz
	15		–		MHz
ON-state frequency response	5		–		MHz
	10		90		MHz
	15		–		MHz

# Quadruple bilateral switches

## HEF4066B gates

	$V_{DD}$ V	TYPICAL FORMULA FOR P ( $\mu$ W)	
Dynamic power dissipation per package (P)	5 10 15	$800 f_i + \sum (f_o C_L) \times V_{DD}^2$ $3\,500 f_i + \sum (f_o C_L) \times V_{DD}^2$ $10\,100 f_i + \sum (f_o C_L) \times V_{DD}^2$	where $f_i$ = input freq. (MHz) $f_o$ = output freq. (MHz) $C_L$ = load capacitance (pF) $\sum (f_o C_L)$ = sum of outputs $V_{DD}$ = supply voltage (V)

### Notes

- $V_{is}$  is the input voltage at a Y or Z terminal, whichever is assigned as input.
- $V_{os}$  is the output voltage at a Y or Z terminal, whichever is assigned as output.
- $R_L = 10\text{ k}\Omega$  to  $V_{SS}$ ;  $C_L = 50\text{ pF}$  to  $V_{SS}$ ;  $E_n = V_{DD}$ ;  $V_{is} = V_{DD}$  (square-wave); see Figs 6 and 10.
- $R_L = 10\text{ k}\Omega$ ;  $C_L = 50\text{ pF}$  to  $V_{SS}$ ;  $E_n = V_{DD}$  (square-wave);  
 $V_{is} = V_{DD}$  and  $R_L$  to  $V_{SS}$  for  $t_{PHZ}$  and  $t_{PZH}$ ;  
 $V_{is} = V_{SS}$  and  $R_L$  to  $V_{DD}$  for  $t_{PLZ}$  and  $t_{PZL}$ ; see Figs 6 and 11.
- $R_L = 10\text{ k}\Omega$ ;  $C_L = 15\text{ pF}$ ;  $E_n = V_{DD}$ ;  $V_{is} = \frac{1}{2} V_{DD(p-p)}$  (sine-wave, symmetrical about  $\frac{1}{2} V_{DD}$ );  $f_{is} = 1\text{ kHz}$ ; see Fig.7.
- $R_L = 1\text{ k}\Omega$ ;  $V_{is} = \frac{1}{2} V_{DD(p-p)}$  (sine-wave, symmetrical about  $\frac{1}{2} V_{DD}$ );

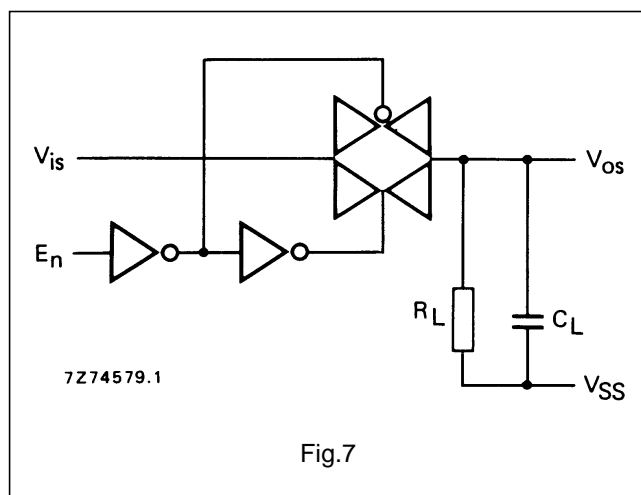
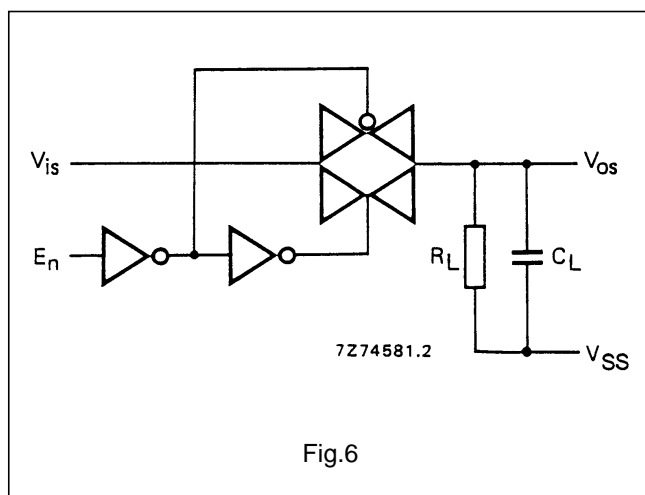
$$20 \log \frac{V_{os}(B)}{V_{is}(A)} = -50 \text{ dB}; E_n(A) = V_{SS}; E_n(B) = V_{DD}; \text{ see Fig. 8.}$$

- $R_L = 10\text{ k}\Omega$  to  $V_{SS}$ ;  $C_L = 15\text{ pF}$  to  $V_{SS}$ ;  $E_n = V_{DD}$  (square-wave); crosstalk is  $|V_{os}|$  (peak value); see Fig.6.
- $R_L = 1\text{ k}\Omega$ ;  $C_L = 5\text{ pF}$ ;  $E_n = V_{SS}$ ;  $V_{is} = \frac{1}{2} V_{DD(p-p)}$  (sine-wave, symmetrical about  $\frac{1}{2} V_{DD}$ );

$$20 \log \frac{V_{os}}{V_{is}} = -50 \text{ dB}; \text{ see Fig. 7.}$$

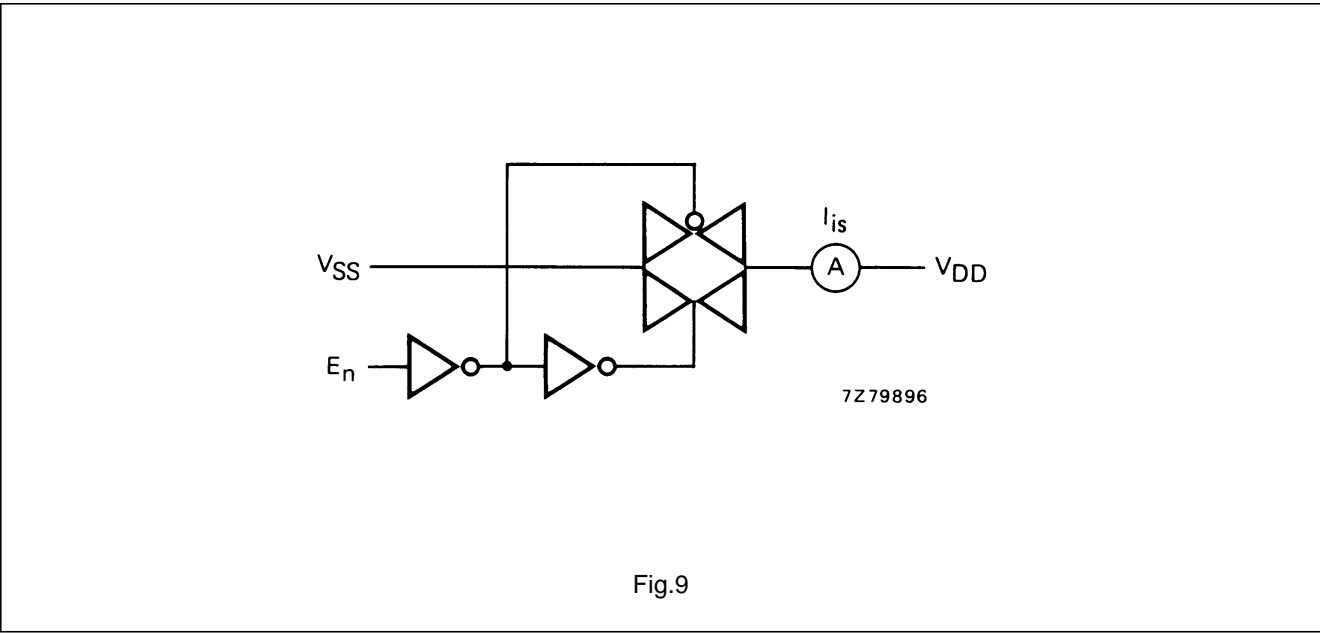
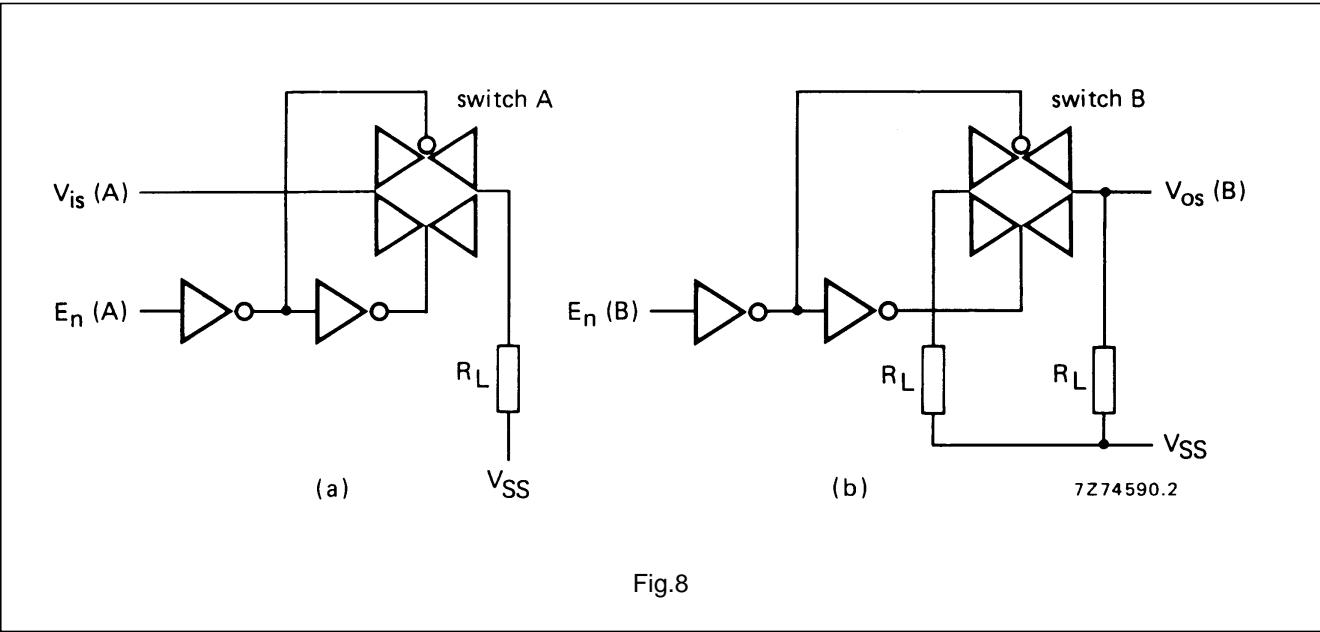
- $R_L = 1\text{ k}\Omega$ ;  $C_L = 5\text{ pF}$ ;  $E_n = V_{DD}$ ;  $V_{is} = \frac{1}{2} V_{DD(p-p)}$  (sine-wave, symmetrical about  $\frac{1}{2} V_{DD}$ );

$$20 \log \frac{V_{os}}{V_{is}} = -3 \text{ dB}; \text{ see Fig. 7.}$$



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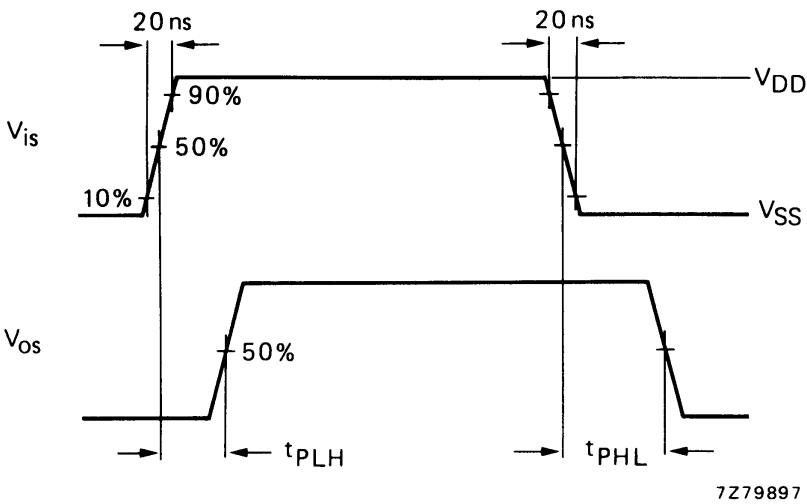
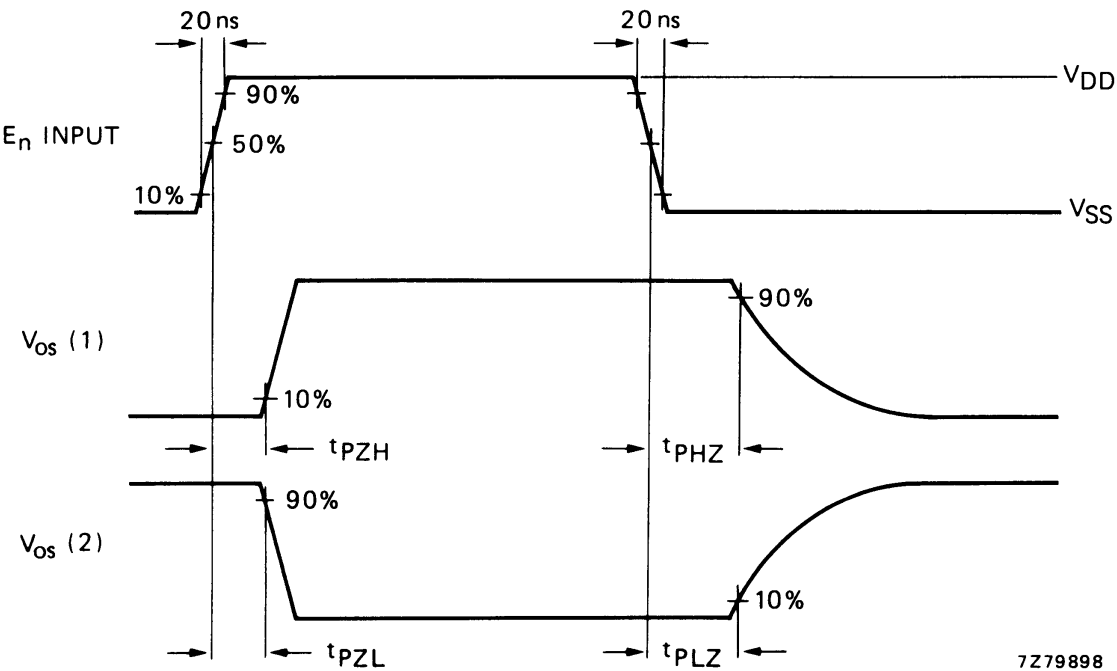


Fig.10 Waveforms showing propagation delays from  $V_{is}$  to  $V_{os}$ .



- (1)  $V_{is}$  at  $V_{DD}$
- (2)  $V_{is}$  at  $V_{SS}$

Fig.11 Waveforms showing output disable and enable times.